OMRON

MOS FET Relays

G3VM-41GR5

New MOS FET Relay with Low Output Capacitance and ON Resistance ($C \times R = 10pF \cdot \Omega$) in a 40-V Load Voltage Model

- \bullet ON resistance of 1 Ω (typical) suppresses output signal attenuation.
- Leakage current of 1.0 nA max. when output relay is open.

■Application Examples

- Semiconductor inspection tools
- Measurement devices
- Broadband systems
- Data loggers



Note: The actual product is marked differently from the image shown here.

■ List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	Surface-mounting	40 VAC	G3VM-41GR5	100	- Marian
terminals			G3VM-41GR5(TR)		2,500

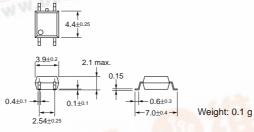
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

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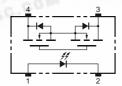


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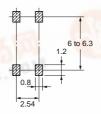
■ Terminal Arrangement/Internal Connections (Top View)

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■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

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Note:

■ Absolute Maximum Ratings (Ta = 25°C)

Item		Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	IF	50	mA	
	Repetitive peak LED forward current	I _{FP}	1	Α	100 μs pulses, 100 pps
	LED forward current reduction rate	Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	V_R	5	V	
	Connection temperature	Tj	125	°C	
Output	Output dielectric strength	V _{OFF}	40	V	
	Continuous load current	I _O	300	mA	
	ON current reduction rate	Δ I _{ON} /°C	-3.0	mA/°C	Ta ≥ 25°C
	Connection temperature	Tj	125	°C	
Dielectr output (Dielectric strength between input and output (See note 1.)		1,500	Vrms	AC for 1 min
Operati	Operating temperature		-20 to +85	°C	With no icing or condensation
Storage	Storage temperature		-40 to +125	°C	With no icing or condensation
Soldering temperature (10 s)			260	°C	10 s

The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

ltem		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions	
Input	LED forward voltage	V_{F}	1.0	1.15	1.3	V	I _F = 10 mA	
	Reverse current	I _R			10	μА	V _R = 5 V	
	Capacity between ter- minals	C _T		15		pF	V = 0, f = 1 MHz	
	Trigger LED forward current	I _{FT}			4	mA	I _O = 100 mA	
Output	Maximum resistance with output ON	R _{ON}		1.0	1.5	Ω	I _F = 5 mA, I _O = 300 mA, t < 1 s	
	Current leakage when the relay is open	I _{LEAK}			1.0	nA	V _{OFF} = 30 V, Ta = 50°C	
	Capacity between ter- minals	C _{OFF}		10.0	14.0	pF	V = 0, f = 100 MHz, t < 1 s	
Capacity between I/O terminals		C _{I-O}		0.8		pF	f = 1 MHz, Vs = 0 V	
Insulation resistance		R _{I-O}	1,000			МΩ	V_{I-O} = 500 VDC, RoH \leq 60%	
Turn-ON time		tON			0.5	ms	$I_F = 10$ mA, $R_L = 200 \Omega$,	
Turn-OFF time		tOFF			0.5	ms	$V_{DD} = 20 \text{ V (See note 2.)}$	

IF J VOUT

Note:

2. Turn-ON and Turn-OFF

■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V _{DD}			32	V
Operating LED forward current	I _F	10		30	mA
Continuous load current	I _O			300	mA
Operating temperature	Ta	25		60	°C

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-41GR5

900 400 400 200 40 60 80 100 Ambient temperature (°C)

■ Safety Precautions

Refer to page 6 for precautions common to all G3VM models.